

# AN6535

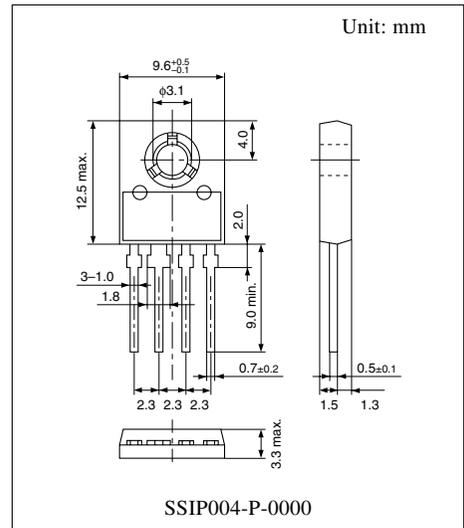
## 4-pin variable negative output voltage regulator

### ■ Overview

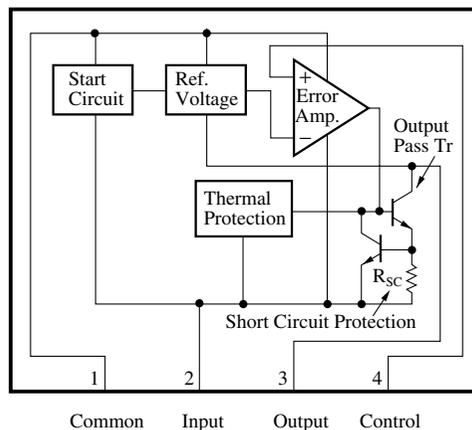
The AN6535 is a monolithic 4-pin variable negative output voltage regulator. With an external resistor, it provides any stabilized output voltages between  $-5V$  and  $-30V$ , and is optimum for the power circuits with a current capacity of up to  $0.5A$ . This IC incorporates various protection circuits.

### ■ Features

- Wide range of output voltages:  $V_O = -5$  to  $-30V$
- Built-in thermal overload protection circuit
- Built-in overcurrent protection circuit
- Built-in ASO (area of safe operation) protection circuit



### ■ Block Diagram



### ■ Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	-40	V
Supply current	$I_{CC}^{*1}$	1	A
Power dissipation	$P_D$	7.5	W
Operating ambient temperature	$T_{opr}$	-20 to +80	$^\circ\text{C}$
Storage temperature	$T_{sig}$	-55 to +150	$^\circ\text{C}$

\*1 The internal circuit is provided with a current limiting circuit.

\*2 Maximum power dissipation value when there is no heat sink (The value varies depending on the external heat radiation state)

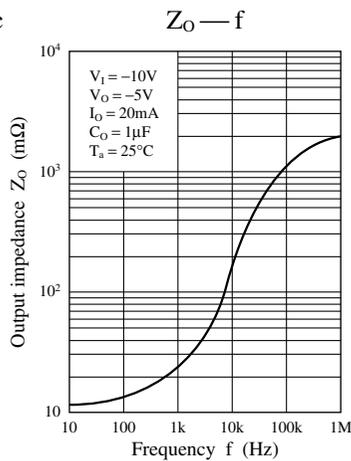
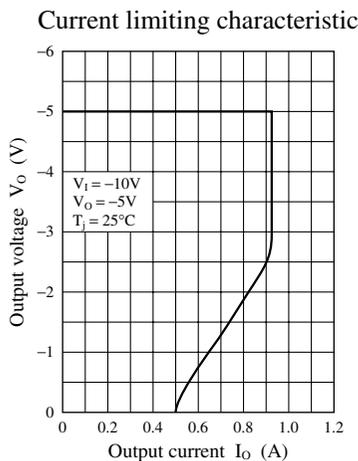
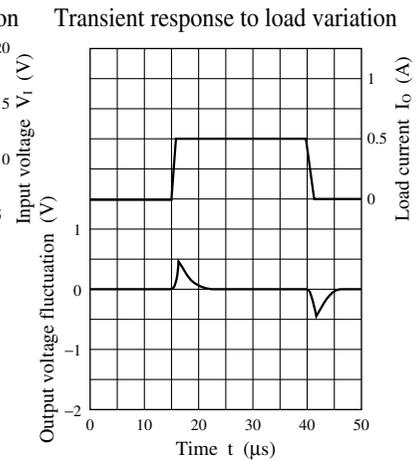
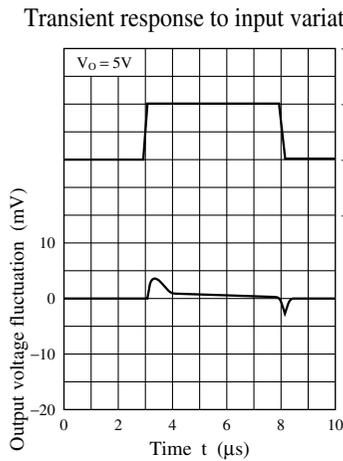
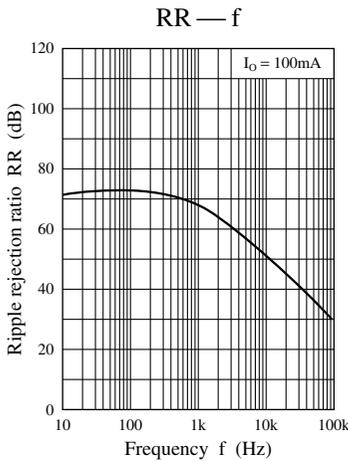
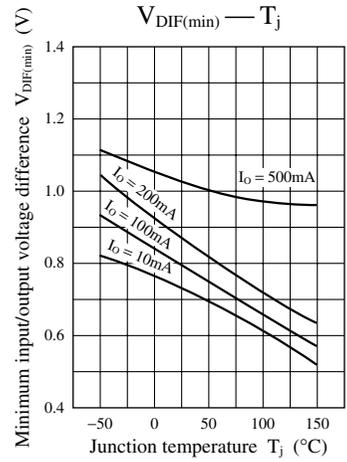
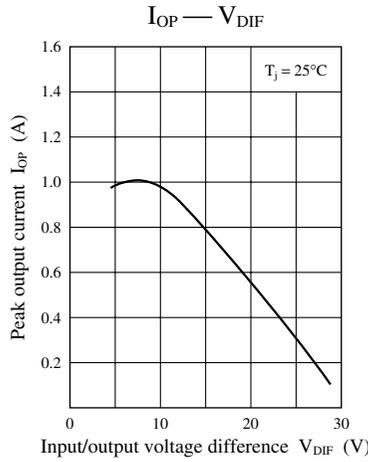
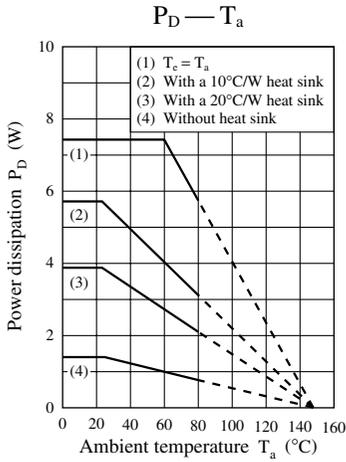
### ■ Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage tolerance	$V_O$	$V_I = V_O - 3\text{V to } V_O - 15\text{V}$ , $I_O = 5 \text{ to } 350\text{mA}$ , $T_j = 25^\circ\text{C}$	—	—	4	%
Line regulation	$REG_{IN}$	$V_O = -5\text{V}$ , $I_O = 200\text{mA}$ , $V_I = -7.5 \text{ to } -25\text{V}$ , $T_j = 25^\circ\text{C}$	—	—	1	%
		$V_O = -18\text{V}$ , $I_O = 5\text{mA}$ , $V_I = -21 \text{ to } -33\text{V}$ , $T_j = 25^\circ\text{C}$	—	—	0.75	%
		$V_O = -18\text{V}$ , $I_O = 200\text{mA}$ , $V_I = -21 \text{ to } -25\text{V}$ , $T_j = 25^\circ\text{C}$	—	—	0.67	%
Load regulation	$REG_L$	$I_O = 5 \text{ to } 500\text{mA}$   $V_O = -5\text{V}$ , $V_I = -12\text{V}$ $T_j = 25^\circ\text{C}$   $V_O = -18\text{V}$ , $V_I = -25\text{V}$	—	—	1	%
Bias current	$I_{Bias}$	$T_j = 25^\circ\text{C}$	—	1.5	3	mA
Control pin current	$I_{cont}$	$T_j = 25^\circ\text{C}$	—	—	3	$\mu\text{A}$
Ripple rejection ratio	RR	$V_I = -8 \text{ to } -18\text{V}$ , $V_O = -5\text{V}$ , $f = 120\text{Hz}$	60	—	—	dB
Output noise voltage	$V_{no}$	$V_O = -5\text{V}$ , $f = 10\text{Hz to } 100\text{kHz}$	—	40	—	$\mu\text{V}$
Minimum input/output voltage difference	$V_{DIF(min)}$	$I_O = 500\text{mA}$ , $T_j = 25^\circ\text{C}$	—	1.1	—	V
Output short-circuit current	$I_{OS}$	$V_I = -35\text{V}$ , $V_O = -5\text{V}$ , $T_j = 25^\circ\text{C}$	—	100	600	mA
Peak output current	$I_{OP}$	$V_O = -5\text{V}$ , $T_j = 25^\circ\text{C}$	0.4	0.8	1.4	A
Output voltage temperature coefficient	$\Delta V_O/T_a$	$V_O = -5\text{V}$   $T_j = -20 \text{ to } +25^\circ\text{C}$ $I_O = 5\text{mA}$   $T_j = 25 \text{ to } 150^\circ\text{C}$	—	0.2	—	mV/ $^\circ\text{C}$
			—	-0.3	—	
Control pin voltage	$V_{cont}$	$T_j = 25^\circ\text{C}$	-3.12	-3	-2.88	V

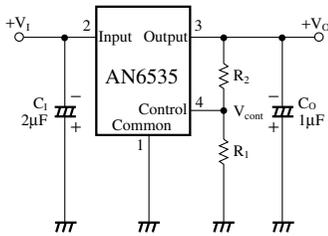
Note 1) The specified condition  $T_j = 25^\circ\text{C}$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = -10\text{V}$ ,  $V_O = -5\text{V}$ ,  $I_O = 350\text{mA}$ ,  $C_1 = 2\mu\text{F}$  and  $C_O = 1\mu\text{F}$

■ Main Characteristics



■ Basic Regulator Circuit



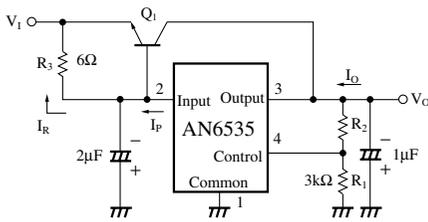
$$V_O = V_{cont} \left( \frac{R_1 + R_2}{R_1} \right)$$

$$(V_{cont} \cong 3V, R_1 = 3k\Omega)$$

C<sub>1</sub> is necessary when the V<sub>1</sub> line is long.  
C<sub>0</sub> improves the transient response.

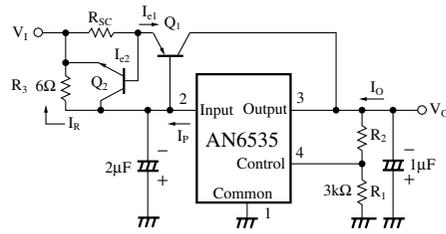
■ Application Circuit Example

1. Current bootstrap circuit



$$R_3 = \frac{V_{BE(Q1)} \cdot \beta}{(\beta + 1) I_P - I_O}$$

2. Current bootstrap circuit (with current limiting circuit)



$$R_{SC} = \frac{V_{BE(Q1)}}{I_{e1(max)}}$$

$$R_3 = \frac{V_{BE(Q1)} + I_{e1} R_{SC}}{I_O - I_{e1}}$$

$$I_{e1(max)} = I_{P(max)} - \frac{V_{BE(Q1)} + V_{BE(Q1)}}{R_3}$$

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